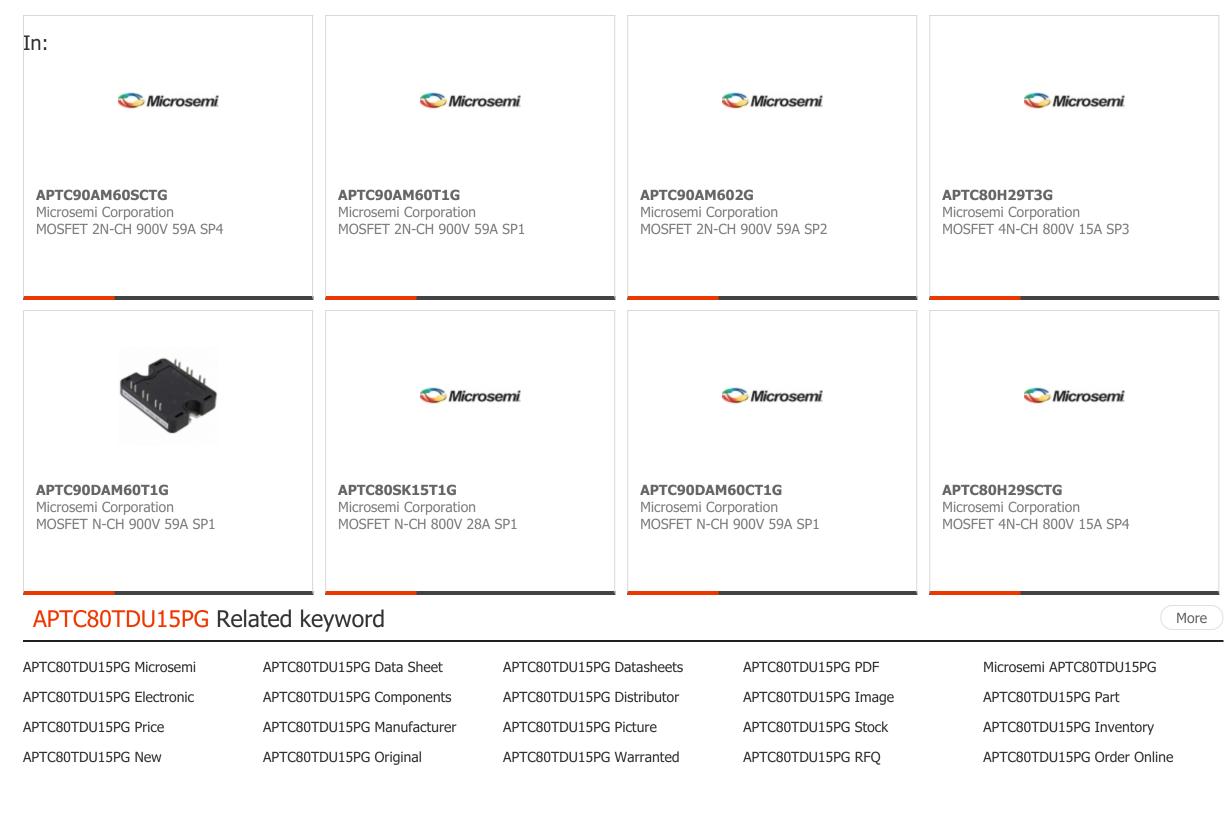




Specifications

Part Number	APTC80TDU15PG
Manufacturer	Microsemi
Description	MOSFET 6N-CH 800V 28A SP6-P
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2587 pcs Stock
Vgs(th) (Max) @ Id	3.9V @ 2mA
Supplier Device Package	SP6-P
Series	-
Rds On (Max) @ Id, Vgs	150 mOhm @ 14A, 10V
Power - Max	277W
Packaging	Bulk
Package / Case	SP6
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Input Capacitance (Ciss) (Max) @ Vds	4507pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	180nC @ 10V
FET Type	6 N-Channel (3-Phase Bridge)
FET Feature	Standard
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	28A

You May Be Also Be interested



Contact us: Info@YIC-Electronics.com

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